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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT3021R

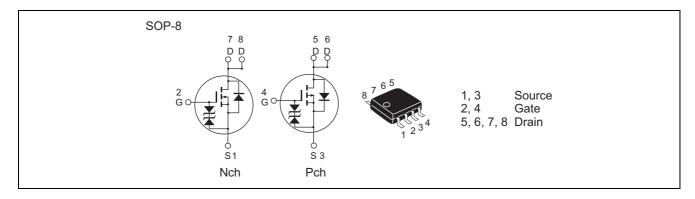
Silicon N/P Channel Power MOS FET Power Switching

REJ03G0415-0200 Rev.2.00 Oct.06.2004

Features

- Capable of 4.5 V gate drive
- Low drive current
- High density mounting

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

ltom	Cumbal	Ra	l lmit	
ltem	Symbol	Nch	Pch	Unit
Drain to source voltage	V_{DSS}	80	-80	V
Gate to source voltage	V_{GSS}	±20	±20	V
Drain current	I _D	3.4	-2.6	А
Drain peak current	I _{D(pulse)} Note1	20.4	-15.6	А
Body-drain diode reverse drain current	I_{DR}	3.4	-2.6	А
Channel dissipation	Pch Note2	1.5	1.5	W
Channel temperature	Tch	150		°C
Storage temperature	Tstg	-55 to +150		°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1 %

2. 1 Drive operation; When using the glass epoxy board (FR4 40 x 40 x 1.6 mm), PW \leq 10s

Electrical Characteristics

 $(Ta = 25^{\circ}C)$

• N Channel

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	80	_	1	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	1	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	± 10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 80 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	_	2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	90	115	mΩ	$I_D = 1.7 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	100	145	mΩ	$I_D = 1.7 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	4.2	7.0	_	S	$I_D = 1.7 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	400	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	57	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	24	_	pF	f = 1 MHz
Total gate charge	Qg	_	7.3	_	nC	V _{DD} = 25 V
Gate to source charge	Qgs	_	1.1	_	nC	V _{GS} = 10 V
Gate to drain charge	Qgd	_	1.3	_	nC	$I_D = 3.4 \text{ A}$
Turn-on delay time	t _{d(on)}	_	6.0	_	ns	$V_{GS} = 10 \text{ V}, I_D = 1.7 \text{ A}$
Rise time	t _r	_	4.0	_	ns	$V_{DD} \cong 30 \text{ V}$
Turn-off delay time	t _{d(off)}	_	39	_	ns	$R_L = 17.6 \Omega$
Fall time	t _f	_	3.5	_	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}	_	0.83	1.08	V	IF = 3.4 A, V _{GS} = 0 Note4
Body-drain diode reverse recovery	t _{rr}	_	30	_	ns	IF = 3.4 A, V _{GS} = 0
time						$diF/dt = 100 A/\mu s$

Notes: 4. Pulse test

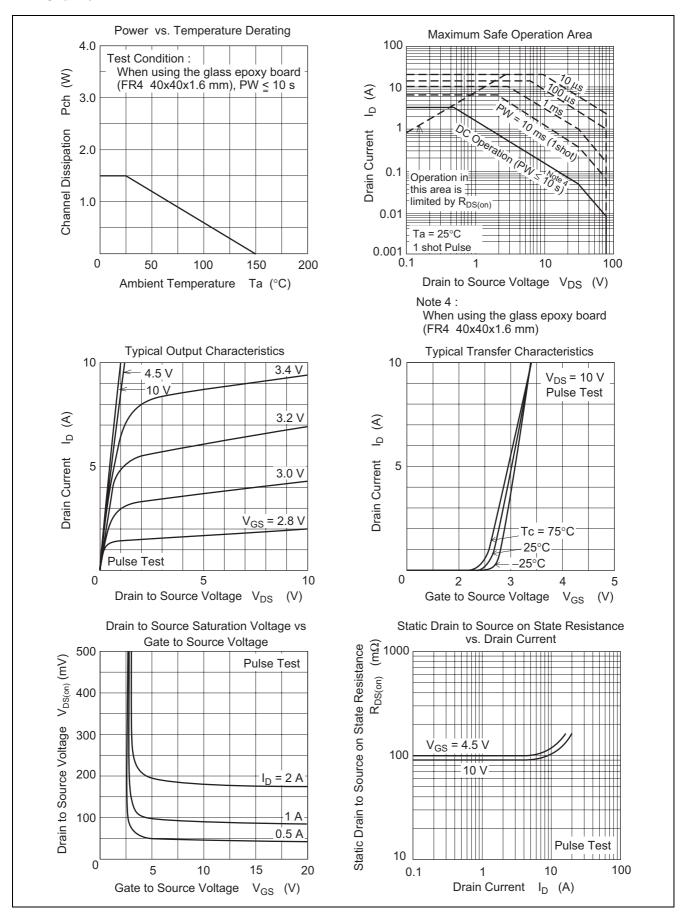
• P Channel

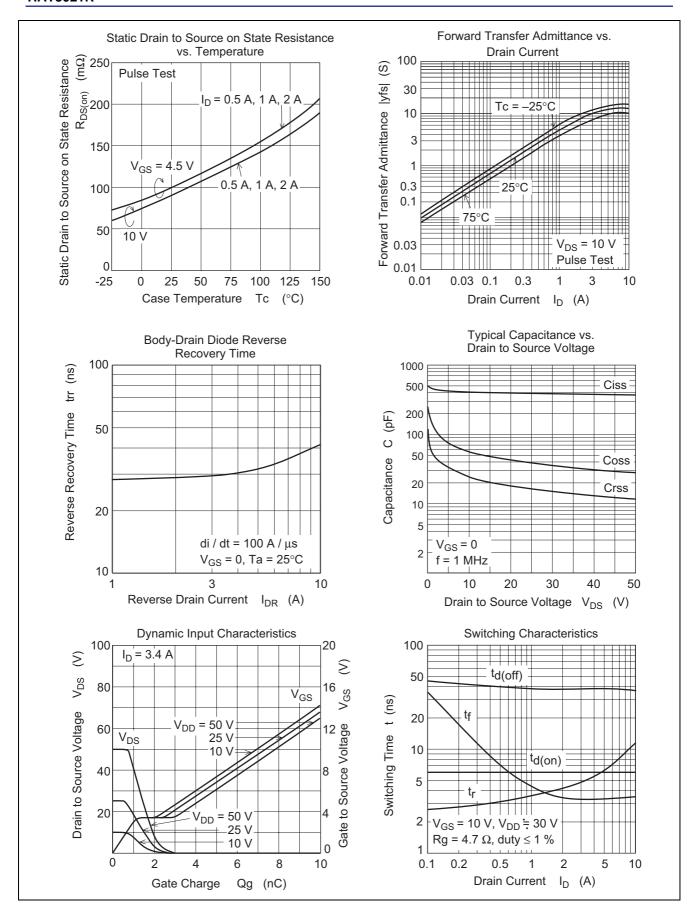
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown	V _{(BR)DSS}	-80	_	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
voltage						
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_G = \pm 100 \mu\text{A}, V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	-1	μΑ	$V_{DS} = -80 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	-1.0	_	-2.5	V	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	165	210	mΩ	$I_D = -1.3 \text{ A}, V_{GS} = -10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	200	290	mΩ	$I_D = -1.3 \text{ A}, V_{GS} = -4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	2.0	3.3	_	S	$I_D = -1.3 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	930	_	pF	$V_{DS} = -10 \text{ V}$
Output capacitance	Coss	_	90	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	56	_	pF	f = 1MHz
Total gate charge	Qg	_	16	_	nC	$V_{DD} = -25 \text{ V}$
Gate to source charge	Qgs	_	2.1	_	nC	$V_{GS} = -10 \text{ V}$
Gate to drain charge	Qgd	_	2.4	_	nC	$I_D = -2.6 \text{ A}$
Turn-on delay time	t _{d(on)}	_	20	_	ns	$V_{GS} = -10 \text{ V}, I_D = -1.3 \text{ A}$
Rise time	t _r	_	12	_	ns	$V_{DD} \approx -30 \text{ V}$
Turn-off delay time	t _{d(off)}	_	40	_	ns	$R_L = 23.0 \Omega$
Fall time	t _f	_	5.5	_	ns	$R_g = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}	_	-0.83	-1.08	V	$IF = -2.6 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body–drain diode reverse recovery time	t _{rr}	_	30	_	ns	$IF = -2.6 \text{ A}, V_{GS} = 0$ diF/ dt =100A/ μ s

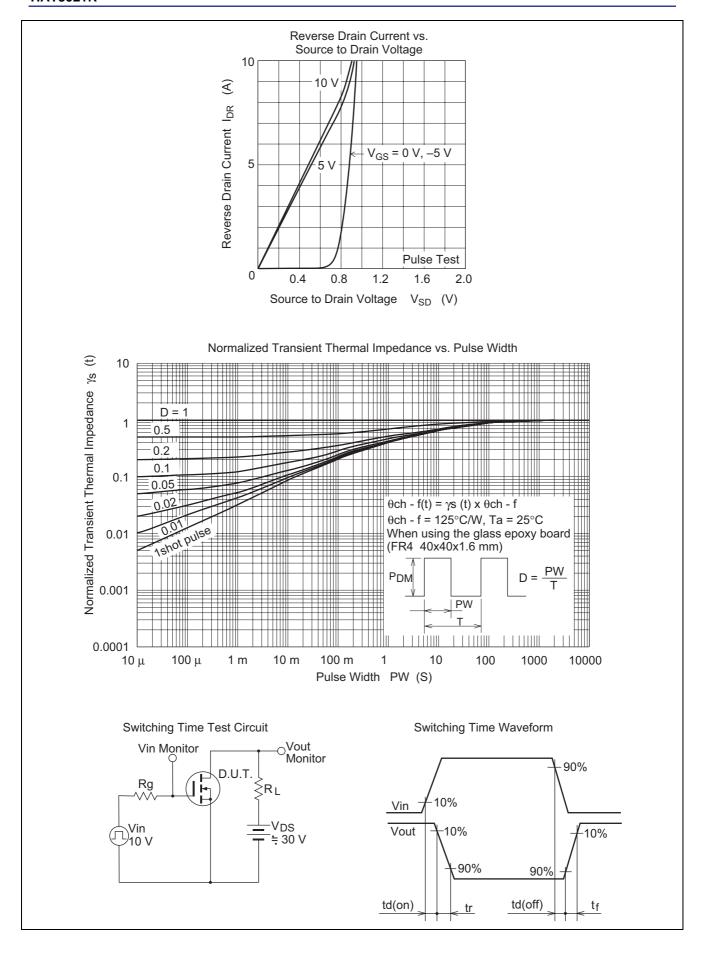
Notes: 4. Pulse test

Main Characteristics

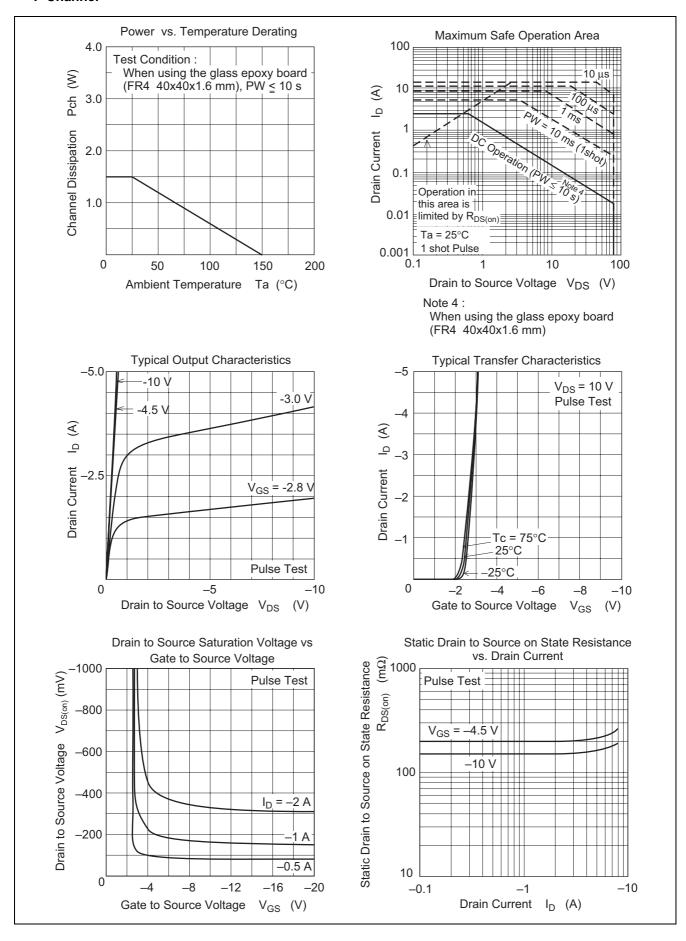
N Channel

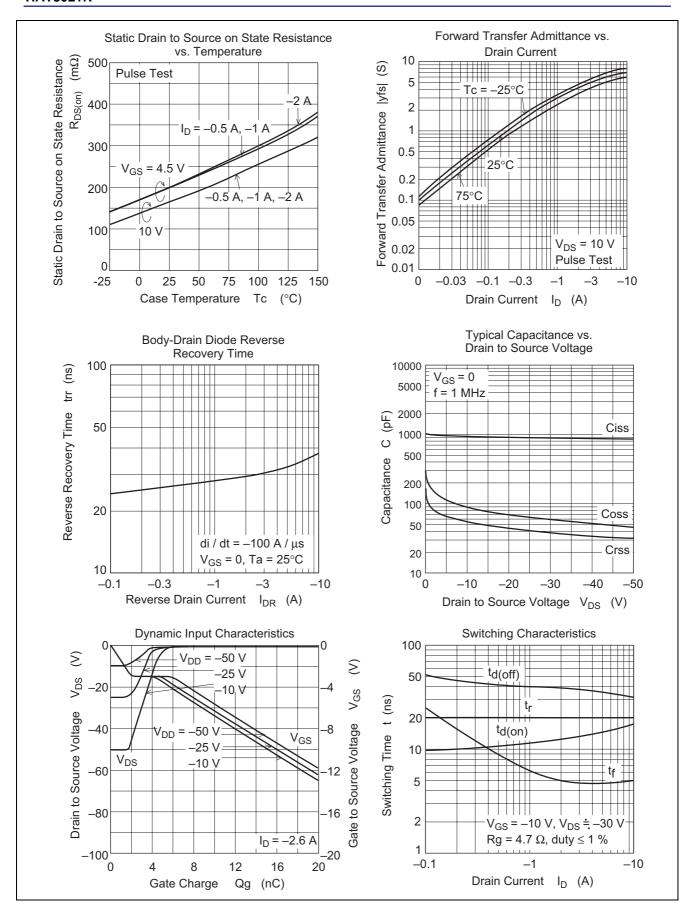


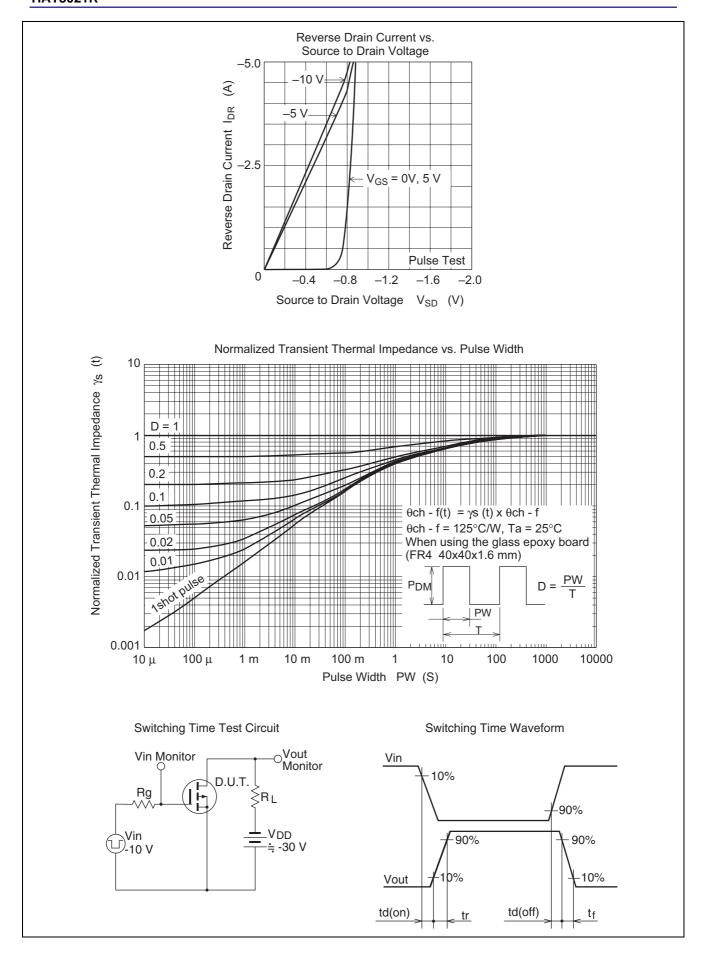




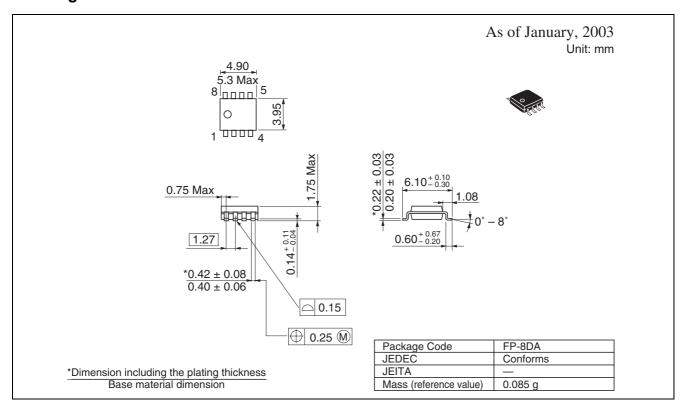
• P Channel







Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container		
HAT3021R-EL-E	2500 pcs	Taping		

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